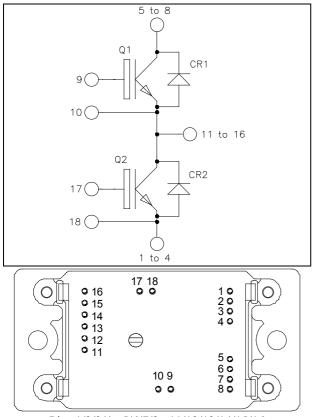
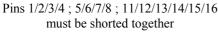


Phase leg Trench + Field Stop IGBT3 Power Module





# APTGT100A602G

## $V_{CES} = 600V$ $I_{C} = 100A(a)$ Tc = 80°C

#### Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

#### Features

- Fast Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
- High level of integration

#### Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive  $T_C$  of  $V_{CEsat}$
- RoHS Compliant

### All ratings (a) $T_i = 25^{\circ}C$ unless otherwise specified

#### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V <sub>CES</sub>	Collector - Emitter Breakdown Voltage		600	V
т	Continuous Collector Current	$T_C = 25^{\circ}C$	150	
I <sub>C</sub>	Continuous Conector Current	$T_C = 80^{\circ}C$	100	Α
I <sub>CM</sub>	Pulsed Collector Current	$T_C = 25^{\circ}C$	200	
V <sub>GE</sub>	Gate – Emitter Voltage		$\pm 20$	V
P <sub>D</sub>	Maximum Power Dissipation	$T_C = 25^{\circ}C$	340	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	200A @ 550V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



## **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I <sub>CES</sub>	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				50	μA
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.5	1.9	V
V <sub>CE(sat)</sub>	Conector Ennitier Saturation Voltage	$I_{\rm C} = 100 {\rm A}$	$T_{j} = 150^{\circ}C$		1.7		v
V <sub>GE(th)</sub>	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 1.5 \text{ mA}$		5.0	5.8	6.5	V
I <sub>GES</sub>	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

## **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		6100		
Coes	Output Capacitance	$V_{CE} = 25V$		390		pF
C <sub>res</sub>	Reverse Transfer Capacitance	f = 1 MHz		190		
Q <sub>G</sub>	Gate charge	V <sub>GE</sub> =±15V, I <sub>C</sub> =100A V <sub>CE</sub> =300V		1.1		μC
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (25°C)		115		
Tr	Rise Time	$V_{GE} = \pm 15V$		45		
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{Bus} = 300V$ $I_{C} = 100A$		225		ns
T <sub>f</sub>	Fall Time	$R_G = 3.3\Omega$		55		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching		130		1
Tr	Rise Time	(150°C)		50		
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$		300		ns
$T_{f}$	Fall Time	$I_{\rm C} = 100 \text{A}$ $R_{\rm G} = 3.3 \Omega$		70		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $T_j = 25^{\circ}C$		0.4		mJ
		$V_{Bus} = 300V$ $T_j = 150^{\circ}C$ $T_j = 100A$ $T_j = 25^{\circ}C$		0.875		
$E_{\text{off}}$	Turn off Energy	$ \begin{array}{c c} I_{\rm C} = 100 {\rm A} & T_{\rm j} = 25^{\circ}{\rm C} \\ R_{\rm G} = 3.3 \Omega & T_{\rm j} = 150^{\circ}{\rm C} \end{array} $		2.5		mJ
		IJ 150 C		3.5		
I <sub>sc</sub>	Short Circuit data	$V_{GE} \le 15V$ ; $V_{Bus} = 360V$ $t_p \le 6\mu s$ ; $T_1 = 150^{\circ}C$		500		А
$R_{thJC}$	Junction to Case Thermal Resistance				0.44	°C/W

## **Reverse diode ratings and characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage			600			V
$I_{RM}$	Maximum Reverse Leakage Current	$V_{R} = 600V$				50	μΑ
I <sub>F</sub>	DC Forward Current		$Tc = 80^{\circ}C$		100		Α
V	$V_{\rm F}$ Diode Forward Voltage $I_{\rm F} = 100 {\rm A} {\rm V}_{\rm GE} = 0 {\rm V}$		$T_i = 25^{\circ}C$		1.6	2	V
• F		$T_{i} = 150^{\circ}C$		1.5		v	
+	Reverse Recovery Time		$T_j = 25^{\circ}C$		125		ns
t <sub>rr</sub>	Reverse Recovery Time		$T_{j} = 150^{\circ}C$		220		115
0	$I_F = 100A$	$T_j = 25^{\circ}C$		4.7			
Q <sub>rr</sub>	Reverse Recovery Charge	$V_{\rm R} = 300 V$ di/dt = 2000 A/µs	$T_{i} = 150^{\circ}C$		9.9		μC
Er	D		$T_j = 25^{\circ}C$		1.1		m I
	Reverse Recovery Energy		$T_{j} = 150^{\circ}C$		2.4		mJ
R <sub>thJC</sub>	Junction to Case Thermal Resistance					0.77	°C/W

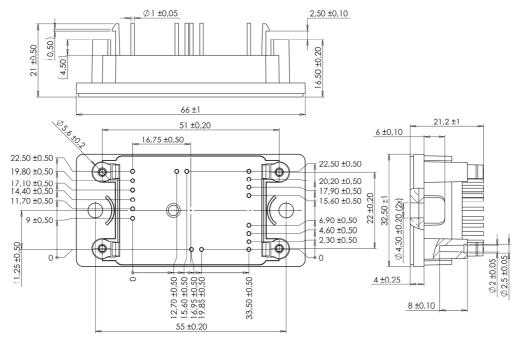


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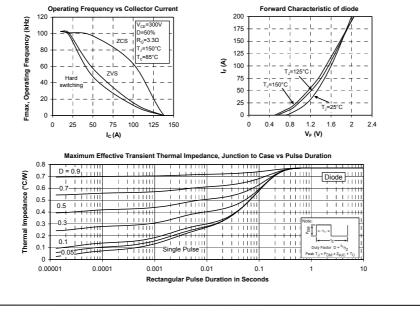
## Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T <sub>J</sub>	Operating junction temperature range		-40		175		
T <sub>STG</sub>	Storage Temperature Range			-40		125	°C
T <sub>C</sub>	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					75	g

### SP2 Package outline (dimensions in mm)



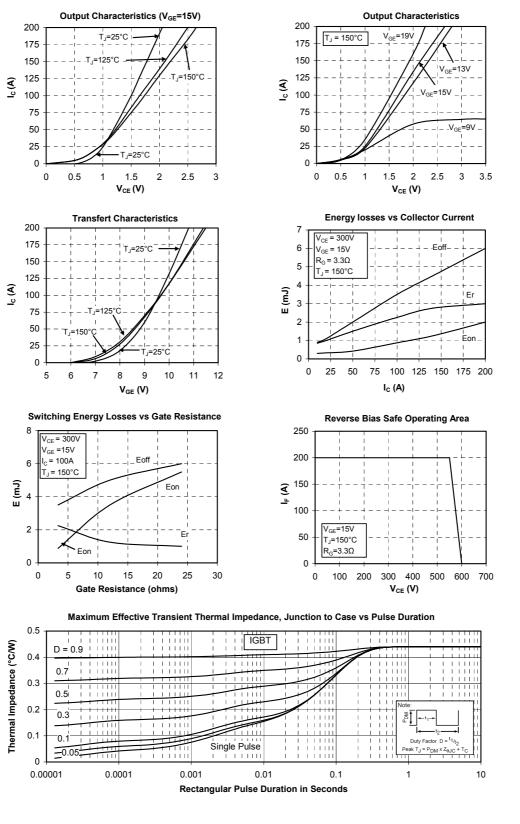
### **Typical Performance Curve**



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# APTGT100A602G

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